



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No. 10/771,593 Confirmation No. 3820  
First Inventor Hamza Yilmaz Filing Date February 2, 2004  
Tech. Center/ 2826 Examiner Fetsum Abraham  
Art Unit  
Title: Semiconductor Device Containing Dielectrically Isolated PN  
Junction For Enhanced Breakdown Characteristics  
Docket No.: YMZ004 US Customer No.: 34036

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Santa Clara, California  
April 26, 2005

Mail Stop Issue Fee  
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P.O. Box 1450  
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AMENDMENT PURSUANT TO 37 CFR 1.312

Dear Sir:

Pursuant to 37 CFR 1.312, please amend the above-identified application as follows.

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 4 of this paper.

**Remarks/Arguments** begin on page 6 of this paper.